



**Advanced Power
Electronics Corp.**

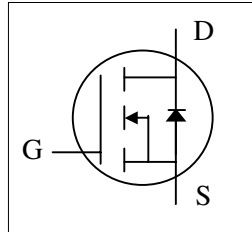
AP10N70R/P-A

RoHS-compliant Product

N-CHANNEL ENHANCEMENT MODE

POWER MOSFET

- ▼ 100% Avalanche Test
- ▼ Fast Switching Characteristic
- ▼ Simple Drive Requirement

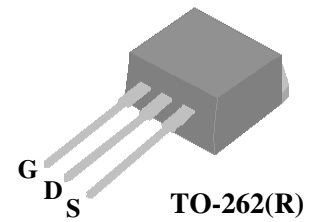


BV_{DSS}	650V
$R_{DS(ON)}$	0.6 Ω
I_D	10A

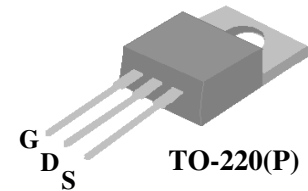
Description

AP10N70 series are specially designed as main switching devices for universal 90~265VAC off-line AC/DC converter applications. Both TO-220 and TO-262 type provide high blocking voltage to overcome voltage surge and sag in the toughest power system with the best combination of fast switching, ruggedized design and cost-effectiveness.

The TO-220 and TO-262 package is widely preferred for commercial-industrial applications. The device is suited for switch mode power supplies, DC-AC converters and high current high speed switching circuits.



TO-262(R)



TO-220(P)

Absolute Maximum Ratings

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	650	V
V_{GS}	Gate-Source Voltage	± 30	V
$I_D@T_C=25^\circ C$	Continuous Drain Current, $V_{GS} @ 10V$	10	A
$I_D@T_C=100^\circ C$	Continuous Drain Current, $V_{GS} @ 10V$	6.8	A
I_{DM}	Pulsed Drain Current ¹	40	A
$P_D@T_C=25^\circ C$	Total Power Dissipation	174	W
	Linear Derating Factor	1.39	W/ $^\circ C$
E_{AS}	Single Pulse Avalanche Energy ²	50	mJ
I_{AR}	Avalanche Current	10	A
T_{STG}	Storage Temperature Range	-55 to 150	$^\circ C$
T_J	Operating Junction Temperature Range	-55 to 150	$^\circ C$

Thermal Data

Symbol	Parameter	Value	Unit
Rthj-c	Maximum Thermal Resistance, Junction-case	0.72	$^\circ C/W$
Rthj-a	Maximum Thermal Resistance, Junction-ambient	62	$^\circ C/W$



Electrical Characteristics@T_j=25°C(unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =1.0mA	650	-	-	V
R _{DS(ON)}	Static Drain-Source On-Resistance	V _{GS} =10V, I _D =5.0A	-	-	0.6	Ω
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250uA	2	-	4	V
g _{fs}	Forward Transconductance	V _{DS} =10V, I _D =5A	-	5	-	S
I _{DSS}	Drain-Source Leakage Current (T _j =25°C)	V _{DS} =600V, V _{GS} =0V	-	-	10	uA
	Drain-Source Leakage Current (T _j =150°C)	V _{DS} =480V, V _{GS} =0V	-	-	100	uA
I _{GSS}	Gate-Source Leakage	V _{GS} = ± 30V	-	-	±100	nA
Q _g	Total Gate Charge ³	I _D =10A	-	35.9	57	nC
Q _{gs}	Gate-Source Charge	V _{DS} =480V	-	8.3	-	nC
Q _{gd}	Gate-Drain ("Miller") Charge	V _{GS} =10V	-	11.5	-	nC
t _{d(on)}	Turn-on Delay Time ³	V _{DD} =300V	-	14.9	-	ns
t _r	Rise Time	I _D =10A	-	19.7	-	ns
t _{d(off)}	Turn-off Delay Time	R _G =10Ω, V _{GS} =10V	-	51.7	-	ns
t _f	Fall Time	R _D =30Ω	-	23.3	-	ns
C _{iss}	Input Capacitance	V _{GS} =0V	-	1950	3120	pF
C _{oss}	Output Capacitance	V _{DS} =15V	-	630	-	pF
C _{rss}	Reverse Transfer Capacitance	f=1.0MHz	-	20	-	pF
R _g	Gate Resistance	f=1.0MHz	-	2	3	Ω

Source-Drain Diode

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
V _{SD}	Forward On Voltage ³	T _j =25°C, I _S =10A, V _{GS} =0V	-	-	1.5	V
t _{rr}	Reverse Recovery Time ³	I _S =10A, V _{GS} =0V,	-	575	-	ns
Q _{rr}	Reverse Recovery Charge	di/dt=100A/μs	-	10.6	-	uC

Notes:

- 1.Pulse width limited by Max. junction temperature.
- 2.Starting T_j=25°C , V_{DD}=50V , L=1.0mH , R_G=25Ω , I_{AS}=10A.
- 3.Pulse test

THIS PRODUCT IS AN ELECTROSTATIC SENSITIVE, PLEASE HANDLE WITH CAUTION.

THIS PRODUCT HAS BEEN QUALIFIED FOR CONSUMER MARKET. APPLICATIONS OR USES AS CRITERIAL COMPONENT IN LIFE SUPPORT DEVICE OR SYSTEM ARE NOT AUTHORIZED.

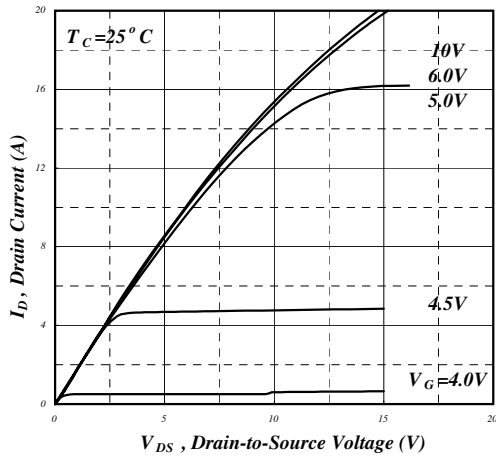


Fig 1. Typical Output Characteristics

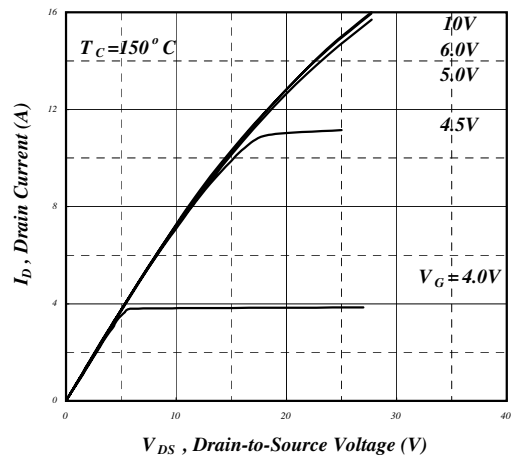


Fig 2. Typical Output Characteristics

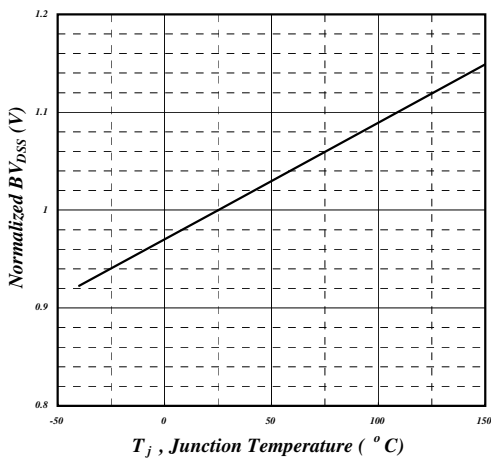


Fig 3. Normalized BV_{DSS} v.s. Junction Temperature

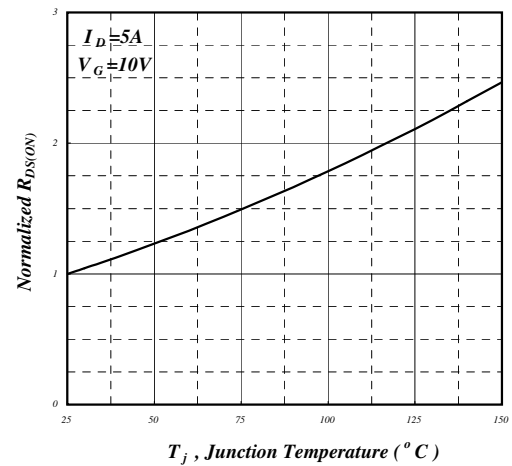


Fig 4. Normalized On-Resistance v.s. Junction Temperature

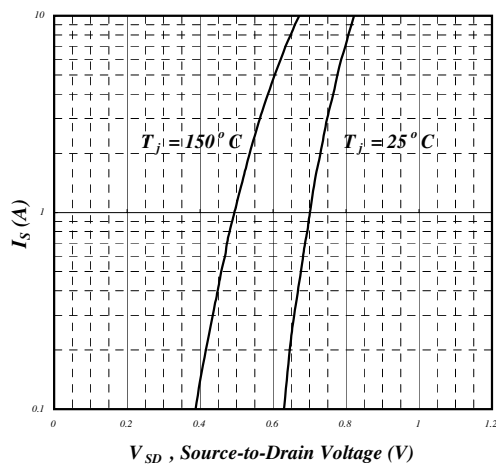


Fig 5. Forward Characteristic of Reverse Diode

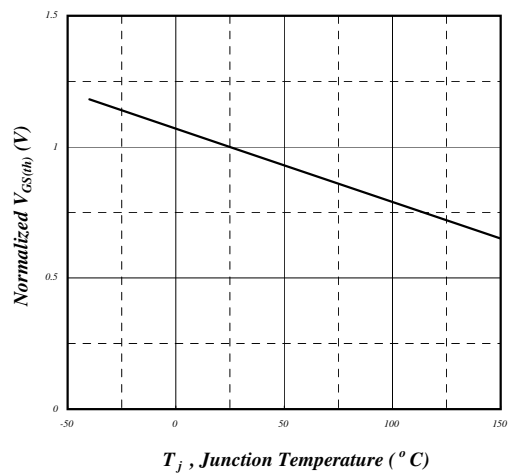
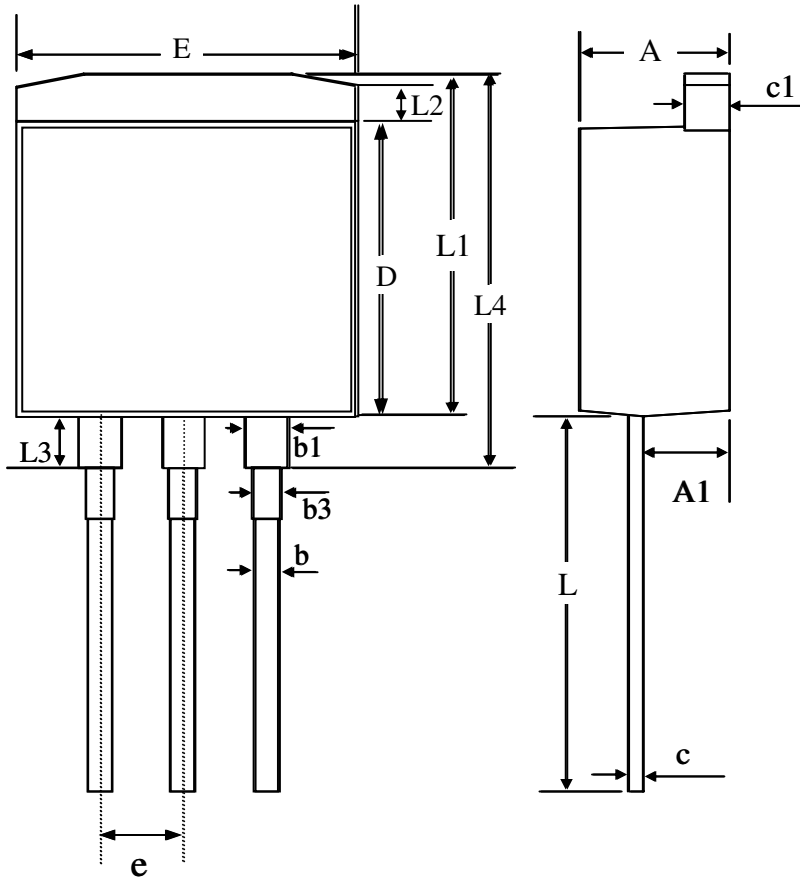


Fig 6. Gate Threshold Voltage v.s. Junction Temperature



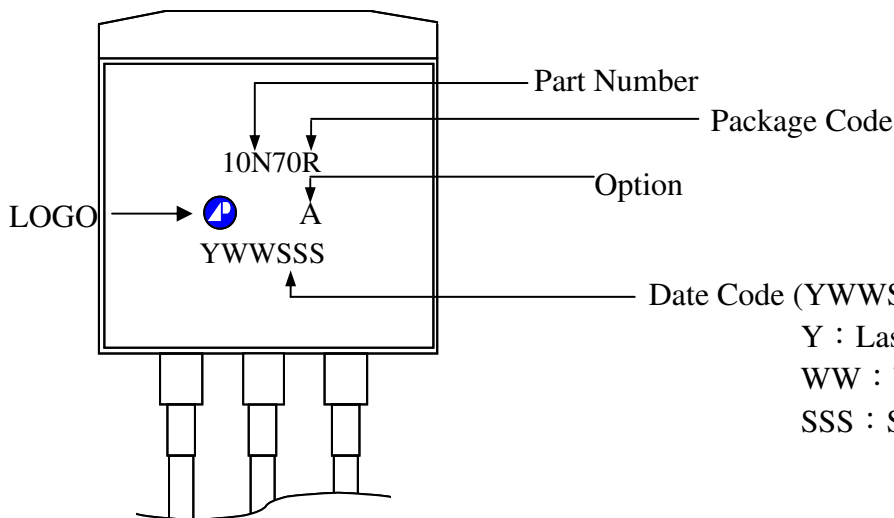
Package Outline : TO-262



SYMBOLS	Millimeters		
	MIN	NOM	MAX
A	4.24	4.44	4.64
A1	-----	-----	2.70
b	0.66	0.76	0.86
b1	1.07	1.27	1.47
b3	0.76	0.86	1.06
c	0.30	0.40	0.50
c1	1.15	1.30	1.45
D	8.30	8.60	8.90
E	9.90	10.20	10.50
e	2.04	2.54	3.04
L	10.50	11.00	11.50
L1	9.50	10.00	10.30
L3	----	1.30	----
L4	10.80	11.30	11.35

- 1.All Dimensions Are in Millimeters.
- 2.Dimension Does Not Include Mold Protrusions.

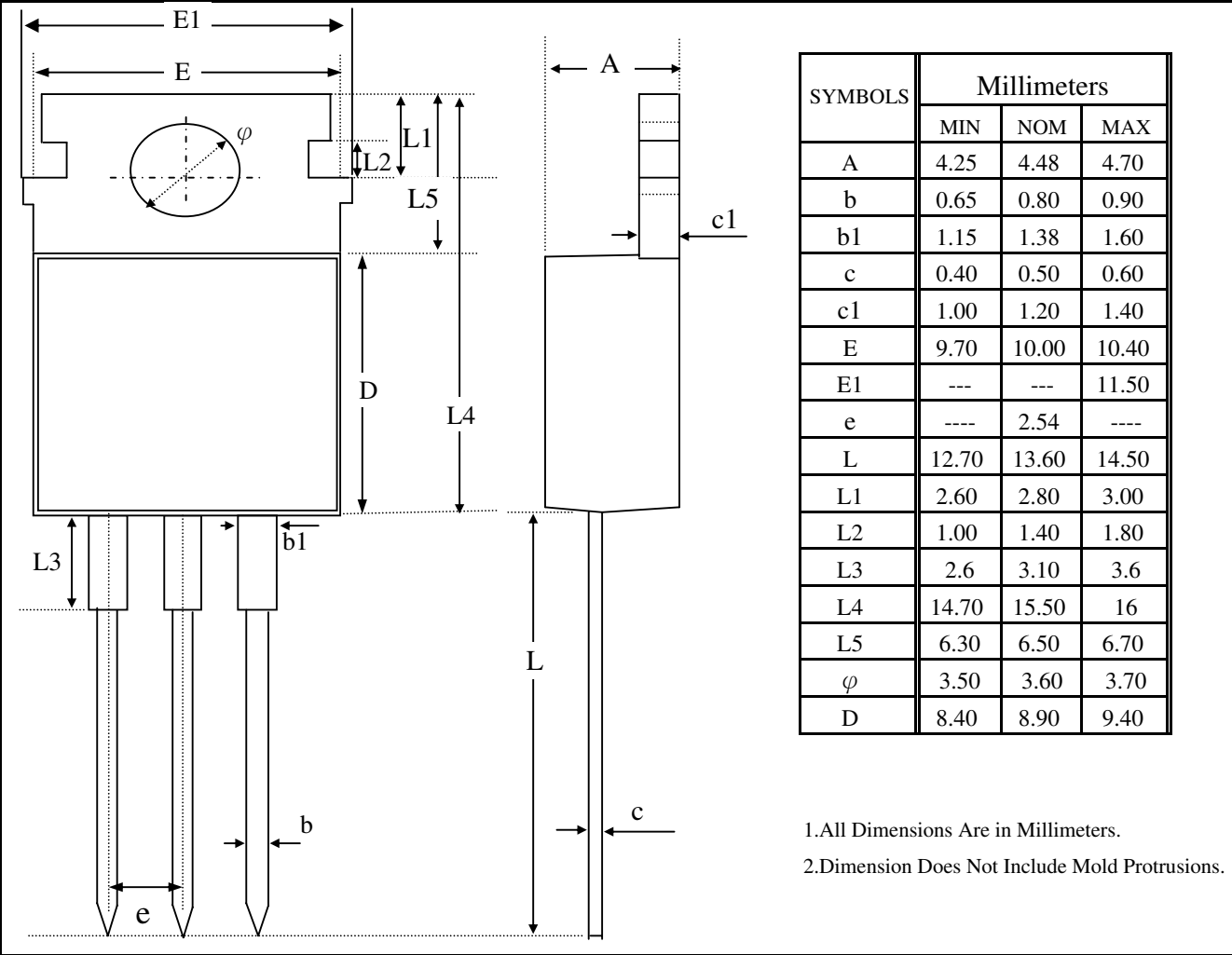
Part Marking Information & Packing : TO-262



Y : Last Digit Of The Year
 WW : Week
 SSS : Sequence



Package Outline : TO-220



Part Marking Information & Packing : TO-220

